

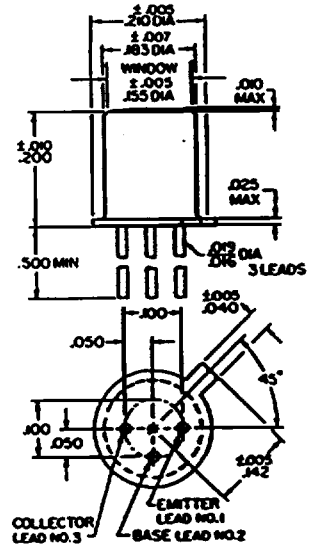


SLR-50F SERIES

NPN SILICON PLANAR EPITAXIAL PHOTODARLINGTON

General Description

The Silonex SLR-50F NPN silicon planar photodarlington series is mounted in a TO-18 flat lensed hermetically sealed package. The flat lensed cap allows an acceptance half angle of 40° measured from the optical axis to the half power point. The first stage base lead is connected for those applications where switching control and circuitry biasing is needed. This series of photodarlington devices is ideal in low light applications where higher gain is needed. Spectrally matched to Silonex infrared emitting diodes.



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

- Collector-Emitter Voltage . . . . . 40
- Collector-Base Voltage . . . . . 60
- Emitter-Base Voltage . . . . . 10
- Storage Temperature Range . . . . .  $-65^\circ\text{C}$  to  $+150^\circ\text{C}$
- Operating Temperature Range . . . . .  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$
- Lead Soldering Temperature (5 Sec, 1/8" from case) . . . . .  $240^\circ\text{C}$
- Power Dissipation . . . . . 250mW
- Derate linearly above  $25^\circ\text{C}$  . . . . .  $2\text{mW}/^\circ\text{C}$

ELECTRICAL CHARACTERISTICS @  $25^\circ\text{C}$

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	SLR-50F1			SLR-50F2			SLR-50F3			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
$I_L (I_{CEO})$	Collector Light Current	$V_{CE} = 5V, H^* = 2\text{mW}/\text{cm}^2$	2			6			14			mA
$I_D (I_{CEO})$	Collector Dark Current	$V_{CE} = 5V, H = 0$			100			100			100	nA
$BV_{CEO}$	Collector to Emitter Break-down Voltage	$I_C = 100\mu\text{A}$	40			40			40			Volts
$BV_{CBO}$	Collector to Base Break-down Voltage	$I_C = 100\mu\text{A}$	60			60			60			Volts
$BV_{EBO}$	Emitter to Base Breakdown Voltage	$I_E = 100\mu\text{A}$	10			10			10			Volts
$V_{CE} (\text{SAT})$	Collector to Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 0.05\text{mA}, H = 0$			1.2			1.2			1.2	Volts
tr	Rise Time	**RL=100Ω, $I_L = 0.5\text{mA}$		100			100			100		μSec
tf	Fall Time	$V_{OC} = 5.0\text{Volts}$		150			150			150		μSec

\*The light source is a frosted Tungsten Incandescent Lamp @  $2870^\circ\text{K}$   
 \*\*The light source is a gallium arsenide LED with a rise time less than 300 ns

\*SIL05002\*